



60V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	Rds(on)	I _D T _A = +25°C
60V	68mΩ @ V _{GS} = 10V	5.6A
00 V	100mΩ @ V _{GS} = 4.5V	4.7A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Motor controls
- · Transformer driving switches
- DC-DC converters
- Power-management functions
- Uninterrupted power supplies

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- · Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

 An automotive-compliant part is available under separate datasheet (<u>DMN6068SEQ</u>)

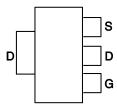
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See diagram below
- Terminals: Finish Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

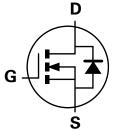
SOT223



Top View



Pin Out - Top View



Equivalent Circuit

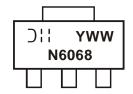
Ordering Information (Note 4)

Part Number	Dackers	Packing		
Part Number	Package	Qty.	Carrier	
DMN6068SE-13	SOT223	4000	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 \bigcirc | | = Manufacturer's Marking N6068 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Year (ex: 4 = 2024) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage		V _{DSS}	60	V	
Gate-Source Voltage		(Note 5)	Vgs	±20	V
Single Pulsed Avalanche Energy		(Note 10)	Eas	37.5	mJ
Single Pulsed Avalanche Current		(Note 10)	I _{AS}	5.0	А
		(Note 7)	I _D	5.6	
Continuous Drain Current	$V_{GS} = 10V$	$T_A = +70^{\circ}C \text{ (Note 7)}$		4.5	Α
		(Note 6)		4.1	
Pulsed Drain Current	Vgs = 10V	(Note 8)	I _{DM}	20.8	А
Continuous Source Current (Body Diode)		(Note 7)	Is	4.9	А
Pulsed Source Current (Body Diode)		(Note 8)	lsм	20.8	А

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)	D	2.0 16.0		
Linear Derating Factor	(Note 7)	PD	3.7 29.5	mW/°C	
The second Decision on the Australian	(Note 6)	Davis	62.5	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	Reja	34		
Thermal Resistance, Junction to Lead	(Note 9)	$R_{ heta JL}$	11.5		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

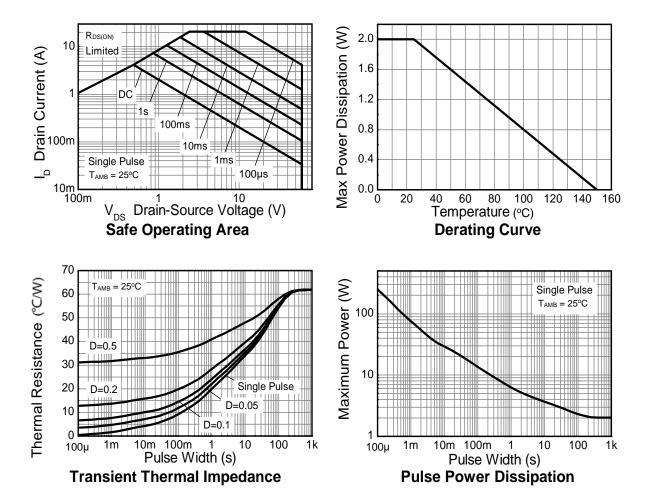
Notes:

- 5. AEC-Q101 V_{GS} maximum is $\pm 16V$.
- 6. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 7. Same as note (6), except the device is measured at $t \le 10$ sec.
- 8. Same as note (6), except the device is pulsed with D = 0.02 and pulse width 300µs. The pulse current is limited by the maximum junction temperature.

 9. Thermal resistance from junction to solder-point (at the end of the drain lead).
- 10. UIS in production with L = 3.0mH, I_{AS} = 5.0A, R_{G} = 25 Ω , V_{DD} = 50V, starting T_{J} = +25°C.



Thermal Characteristics





Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

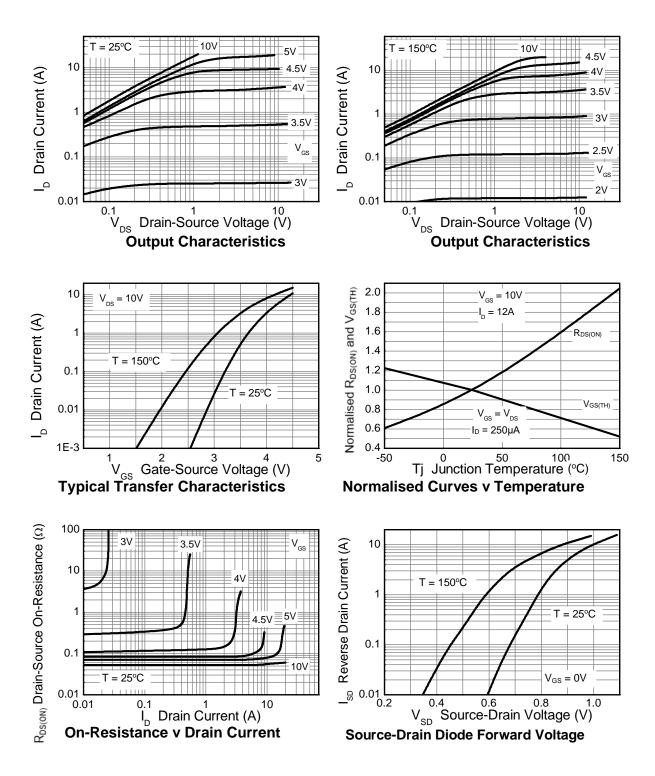
Characteristic	Symbol	Min	Тур	Max	Unit	Test (Condition	
OFF CHARACTERISTICS								
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	I _D = 250μA, V _{GS} = 0V		
Zero Gate Voltage Drain Current	I _{DSS}	_	_	0.5	μΑ	$V_{DS} = 60V, V_{GS}$	= 0V	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{D}$	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS	•		•	•				
Gate Threshold Voltage	Vgs(TH)	1.0	_	3.0	V	$I_D = 250 \mu A, V_D$	s = Vgs	
Static Dunin Course On Desigtance (Note 44)	-			0.068	Ω	Vgs = 10V, ID =	12A	
Static Drain-Source On-Resistance (Note 11)	RDS(ON)			0.100		Vgs = 4.5V, ID =	= 6A	
Forward Transconductance (Notes 11 & 12)	g fs	_	19.7	_	S	V _{DS} = 15V, I _D =	12A	
Diode Forward Voltage (Note 11)	VsD	_	0.98	1.15	V	Is = 12A, Vgs =	0V	
Reverse recovery time (Note 12)	trr	_	145	_	ns	I _S = 12A, di/dt= 100A/μs		
Reverse recovery charge (Note 12)	Qrr	_	929	_	nC			
DYNAMIC CHARACTERISTICS (Note 12)								
Input Capacitance	Ciss		502	_	pF	V _{DS} = 30V, V _{GS} = 0V f = 1MHz		
Output Capacitance	Coss	_	45.7	_	pF			
Reverse Transfer Capacitance	Crss	_	27.1	_	pF			
Total Gate Charge (Note 13)	Qg	_	5.55	_	nC	V _{GS} = 4.5V		
Total Gate Charge (Note 13)	Qg	_	10.3	_	nC		V _{DS} = 30V	
Gate-Source Charge (Note 13)	Qgs	_	1.6	_	nC	V _{GS} = 10V		
Gate-Drain Charge (Note 13)	Qgd	_	3.5	_	nC			
Turn-On Delay Time (Note 13)	tD(ON)	_	3.6	_	ns			
Turn-On Rise Time (Note 13)	t _R	_	10.8	_	ns	$V_{DD} = 30V, V_{GS} = 10V$ $I_{D} = 12A, R_{G} \cong 6.0\Omega$		
Turn-Off Delay Time (Note 13)	tD(OFF)		11.9	_	ns			
Turn-Off Fall Time (Note 13)	tF	_	8.7	_	ns			

Notes:

^{11.} Measured under pulsed conditions. Pulse width ≤ 300µs; duty cycle ≤ 2%.
12. For design aid only, not subject to production testing.
13. Switching characteristics are independent of operating junction temperatures.

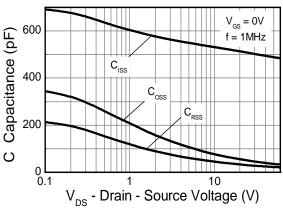


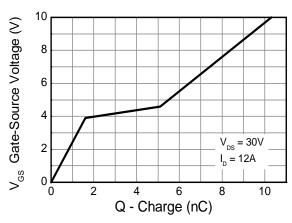
Typical Characteristics





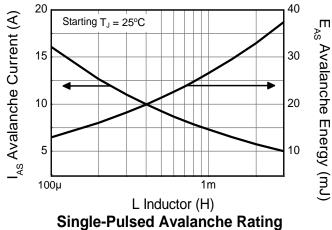
Typical Characteristics (continued)





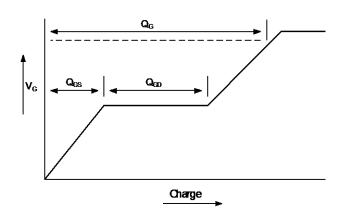
Capacitance v Drain-Source Voltage

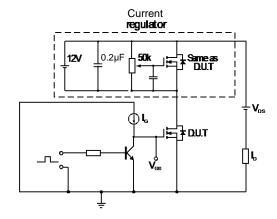
Gate-Source Voltage v Gate Charge





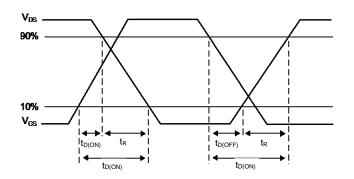
Test Circuits

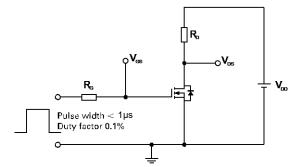




Basic gate charge waveform

Gate charge test circuit





Switching time waveforms

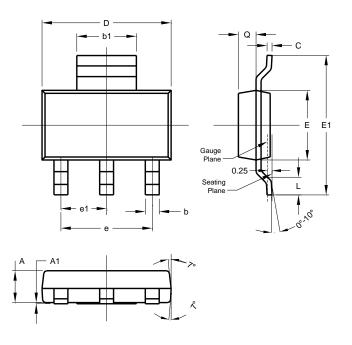
Switching time test circuit



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223

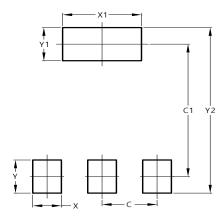


SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
C	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Ø	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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DMN6068SE 9 of 9 March 2024

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